Conventional Transmission Electron Microscopy (CTEM) understanding contrast of crystal defects

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Florent Houdellier CEMES-CNRS, 29 rue jeanne marvig 31055 Toulouse and DGP-INSA,135 avenue de rangueil 31400 Toulouse



- Sample morphology (grain size, precipitate size, etc.)
- Crystal defects (dislocations, faults, grain boundaries, etc.)
- Crystalline symmetries (point and space groups)
- Crystalline and non-crystalline materials

Atomic scale ?



What is CTEM ?

What is conventional microscopy ? Structural characterization :

Diffraction contrast !











Example : what kind of informations are required to study dislocations in materials ?

local

(the core of the dislocations governs their mobility)

Nanometric scale : High resolution

Mesoscopic domain :

- Very fine structure (atomic scale)
- Not easy to use (surface-dependent)



Why CTEM ?



global (geometry and organisation)

Macroscopic region (SEM or **Optical methods**)

- Slip traces
- Slip plans
- Burgers vectors activated
- No local information









- Area observed : from $50 \mu m^2$ to $1 \mu m^2$



Why CTEM ?



• Magnification neither too small nor too large : x 10 000 to x 100 000

• Requires a standard microscope (not necessary coherent nor corrected)





Diffraction theory of perfect crystal

Kinematical theory Amplitude-Phase diagram Howie-Whelan approach to dynamical effect

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Atomic form factor





See Doyle-Turner or Weickenmeir-Kohl diffusion coefficients in International table of crystallographic







Diffraction by a periodic set of diffusion sites







$$B_i s^2 e^{-2\pi \overrightarrow{g} \cdot \overrightarrow{r}_i}$$

$$S_{\overrightarrow{K}} \qquad I_{\overrightarrow{g}} \approx |F_{\overrightarrow{g}}|^2 |S_{\overrightarrow{K}}|^2$$

$$u^{2} >$$





Introduction to electron diffraction theory : the Bragg law



The diffraction pattern can be deduced from the intersection of a sphere called the Ewald sphere with the reciprocal crystal lattice :













Introduction to electron diffraction theory : geometry of a diffraction pattern



Diffraction in a TEM and image formation : the Abbe theory of imaging

















(EM)}

Selected area electron diffraction (SAED) : strength of the TEM





Selected area aperture





(I) Example of conventional diffraction analysis : mono vs poly / crystal







• The kikuchi lines (and the spot intensities) are « attached » to the sample tilt











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Kikuchi lines : zone axis pattern (ZAP)















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The rocking curve











Mapping of the rocking curves : the convergent beam electron diffraction pattern (CBED)









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Shape transforms











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Huygens-Fresnel principle : spherical wave propagation



Huygens-Fresnel principle :

The secondary wave amplitude at the point P

is obtained by summing the amplitudes

of the spherical wavelets from a spherical wavefront of radius r.



(I) Incoming spherical wave :

$$\psi = A_Q \frac{e^{2\pi i k r}}{r}$$

(II) Huygens-Fresnel principle : from each point, emission of wavelets :

$$d\psi = K(\theta)\psi \frac{e^{2\pi i kR}}{R} dS \qquad K(\theta) = \frac{1 + \cos(\theta)}{2} \frac{1}{i\lambda} =$$

$$\Psi(P) = \iint_{S} d\psi = \iint_{S} K(\theta)\psi \frac{e^{2\pi i kR}}{R} d\xi$$

(III) Integration variable change due to wavefront geometry

$$dS = rd\chi 2\pi r \mathbf{sin}(\chi) \qquad R = r^2 = r^2 + (r + R_0)^2 - 2r(r + R_0)^2$$
$$dS = 2\pi \left(\frac{r}{(r + R_0)}\right) R dR$$

$$\psi(P) = \frac{2\pi\psi}{i\lambda(r+R_0)} \int_{R_0}^{R_{max}} A(\theta) e^{2\pi i kR} dR$$





$$\int_{R_0}^{\infty} A(\theta) e^{2\pi i kR} dR = \frac{1}{2} \int_{R_0}^{R_0 + \frac{\lambda}{2}} e^{2\pi i kR} dR = \frac{i}{2\pi k} e^{2\pi i kR_0} \psi(P) = A_Q \frac{e^2}{k}$$







For an incoming plane wave we have $(n \to \infty \implies \theta_n \to 90^\circ)$

Fresnel zones rules : plane wave propagation

$$\psi_n = (1 + \cos(\theta_n))(-1)^{n+1}e^{2\pi i k z}$$

+...+(
$$|\psi_{N-1} - \psi_{N-2}|) - |\psi_N|$$

$$|\psi_1| - |\psi_N|$$

:
$$\psi(P) = 2e^{2\pi i kz} - e^{2\pi i kz} = e^{2\pi i kz}$$

The secondary wavefront in *P* remains *a plane wave*









Application of Fresnel zones : Fresnel fringes







Evaluation of Fresnel integral using APD (Cornu's spiral) Converge to $\pm \left(\frac{1}{2}, \frac{1}{2}\right)$ as *s* moves from $0 \to \pm \infty$



$$\oint \phi(x, y) \propto \left[\left(\frac{1}{2} + i \frac{1}{2} \right) - \left(\overline{X} + i \overline{Y} \right) \right]$$







Application of Fresnel zones : Fresnel Fringes













• Let's consider an incoming plane wave ψ_0 on a crystal define by a thickness t

- Electrons wavelength : $\lambda = 3,7 \text{pm} \rightarrow (100 \text{keV})$
- Radius of the first Fresnel zone : $\rho_1 = \sqrt{R_0 \lambda}$

 \Rightarrow We want to estimate the contribution of the slice dz to $\psi_{\overrightarrow{g}}(P)$ (I) For $R_0 = 100$ nm we have $\rho_1 = 0.6$ nm

This means that only a column with a diameter of 1 - 2nm is contributing to the amplitude at the point P. We will only consider this first Fresnel zone.

• The method is therefore called the **column approximation**. (II)There are $\frac{dz}{dz}$ unit cells per unit area in an element of thickness dz. Thanks to Huygens-Fresnel Principe the contribution $d\psi_{\overrightarrow{g}}$ of this element is :

$$d\psi_{\overrightarrow{g}} = \psi_0 \frac{dz}{V_e} \iint F_{\overrightarrow{g}}(\theta) \frac{e^{2\pi i kR}}{R} dS = \psi_0 \frac{2\pi dz}{V_e} \int_{R_0}^R F_{\overrightarrow{g}}(\theta) e^{2\pi i kR} dR$$
$$K(\theta) = F_{\overrightarrow{g}}(\theta)$$





Diffraction intensity under column approximation

Integral estimation using APD : (III) To estimate the diffracted intensity $I_{\overrightarrow{g}}$ we simply have to integrate $d\psi_{\overrightarrow{g}}$ over the thickness Imaginary axis dzBecause of column approx \vec{s} and \vec{r} are collinear : $\vec{s} \cdot \vec{r} = sz$ $l\pi$ $e^{2\pi i k_0 t}$ $2\pi i sz dz$ $\psi_{\overrightarrow{g}}$ $\xi \rightarrow q$ $2\pi s$ $=2\pi sz$ ► Real axis $I_0 = 1 - I_{\overrightarrow{g}}$

$$R_{0} = t - z$$

$$|\psi_{0}| = 1$$

$$\psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} e^{2\pi i k_{0} t} \int_{0}^{t} e^{-2\pi i (\overrightarrow{g} + \overrightarrow{s}).\overrightarrow{r}}$$

$$\overrightarrow{k} = \overrightarrow{k}_{0} + \overrightarrow{g} + \overrightarrow{s}$$



(IV) We will now always estimate this Fresnel integral, and $I_{\overrightarrow{g}}$, using APD (phasor)

$$\bullet \qquad I_{\overrightarrow{g}} = \psi_{\overrightarrow{g}}\psi_{\overrightarrow{g}}^* = \frac{\pi^2}{\xi_{\overrightarrow{g}}^2} \frac{\sin^2(\pi ts)}{(\pi s)^2}$$







Going back to the diffracted intensities : the kinematical rocking curve ([]]]} $I_{\overrightarrow{g}} = \psi_{\overrightarrow{g}} \psi_{\overrightarrow{g}}^* = \frac{\pi^2 \operatorname{sin}^2(\pi ts)}{\xi_{\overrightarrow{g}}^2}$ CBED kinematical lines profile = rocking curve $s \doteq 0$









Introduction to dynamical theory

Kinematical approach :

only one interaction from each dz element









Dynamical approach :

Multiple interactions, from each dz element













Step by step derivation of Howie-Whelan equations : 2-beams dynamical theory

Let's consider the phase origin located in O. All the demonstration will previous results obtained using Huygens-Fresnel approach

A point will affect the incoming wave ψ_0 by the value $d\psi_{\overrightarrow{g}} = \frac{i\pi}{\xi} \psi_0 e^{2\pi i k R_0} dz$

note
$$q = \frac{a\pi}{\xi_{\overrightarrow{g}}}$$

 \rightarrow The ratio between the wave amplitude coming from OAfter crossing *B* is $\frac{|\psi(B)|}{|\psi(O)|} = iq$. Then after crossing *A* we have $\frac{|\psi(A)|}{|\psi(O)|} = iq_0$

(I) The wave starting from O and arriving in A is : $\psi_0(p, n)e^{2\pi i(\vec{k}_0 \cdot \vec{OA})}$

After crossing A we add the point contribution the wavefront becomes : $\psi_0(p,n)(1+iq_0)e^{2\pi i(\vec{k}_0.\vec{OA})}$

(II) The wave diffracted from I and arriving in A is : $\psi_{\overrightarrow{g}}(p+2,n)e^{2\pi i \overrightarrow{k}_{\overrightarrow{g}}}(\overrightarrow{HI}+\overrightarrow{IA})$

After crossing A the wavefront along \vec{k}_0 becomes : $iq\psi_{\overrightarrow{g}}(p+2,n)e^{2\pi i \overrightarrow{k}_{\overrightarrow{g}}.(\overrightarrow{HI}+\overrightarrow{IA})}$

And along \vec{k} we add the point contribution to the incoming wavefront $(1 + iq_0)\psi_{\overrightarrow{g}}(p + 2,n)e^{2\pi i \overrightarrow{k}_{\overrightarrow{g}}.(\overrightarrow{HI} + \overrightarrow{IA})}$















Step by step derivation of Howie-Whelan equations : 2-beams dynamical theory

$$\vec{A} = 2\pi \bar{k}_0 \cdot \overline{OA} = \frac{2\pi \bar{k}_0 d}{\sin(\theta)} = \delta$$

$$\vec{HI} + \vec{IA} = 2\pi \vec{k}_{\vec{g}} \cdot \vec{HI} + 2\pi \vec{k}_{\vec{g}} \cdot \vec{IA} = 2\pi \bar{k}_{\vec{g}} \cdot \vec{HI} + 2\pi \bar{k}_{\vec{g}} \cdot \vec{IA} = \phi + \delta$$

$$\begin{cases} \psi_0(p+1,n+1)e^{-i\delta} = (1+iq_0)\psi_0(p,n) + iq\psi_{\vec{g}}(p+2,n)e^{i\phi} \\ \psi_{\vec{g}}(p+1,n+1)e^{-i\delta} = (1+iq_0)\psi_{\vec{g}}(p+2,n)e^{i\phi} + iq\psi_0(p,n)e^{i\phi} \end{cases}$$

(III) We will now consider the Friedel Law : $\psi_{\overrightarrow{g}} = \psi_{-\overrightarrow{g}}$ and some first geometrical simplifications

$$+ \delta\theta \quad \sin(\delta\theta) \approx 0, \cos(\delta\theta) \approx 1 \quad e^{-i\delta} \approx 1$$

$$+ 2d\delta\theta\cos(\theta_B) = \lambda + 2ds \frac{\cos(\theta_B)}{g} = \lambda + 2d^2s\cos(\theta_B)$$

$$g = \frac{d}{a_B} \quad \clubsuit \quad \phi = \frac{2\pi}{\lambda} \left(\lambda + 2d^2s\sin(\theta_B)\frac{a_B}{d}\right) = 2\pi(1 + a_Bs) \quad \clubsuit \quad e^{i\phi} = e^{i\phi}$$

 $e^{i\phi}iq \approx iq$ $e^{i\phi}(1+iq_0) \approx 1+iq_0$ (IV) We will now do first linear approximation :

$$\psi_0(p+1,n+1) - \psi_0(p,n) = iq_0\psi_0(p,n) + iq\psi_{\overrightarrow{g}}(p+2,n)$$

$$\psi_{\overrightarrow{g}}(p+1,n+1) - \psi_{\overrightarrow{g}}(p+2,n) = i(q_0 + \phi)\psi_{\overrightarrow{g}}(p+2,n) + iq\psi_0(p,n)$$









Step by step derivation of Howie-Whelan equations : 2-beams dynamical theory

(V) Introducing differential operators thanks to Taylor development :

$$+1,n+1) - \psi_0(p,n) = \frac{\partial \psi_0}{\partial x}(x_{p+1} - x_p) + \frac{\partial \psi_0}{\partial z}(z_{n+1} - z_n)$$
$$p + 1,n+1) - \psi_{\overrightarrow{g}}(p+2,n) = \frac{\partial \psi_{\overrightarrow{g}}}{\partial x}(x_{p+1} - x_{p+2}) + \frac{\partial \psi_{\overrightarrow{g}}}{\partial z}(z_{n+1} - z_n)$$

(VI) Considering that the amplitude depends only on the variable z, the two equations become a first system of differential equations (column approximation) :

$$= \begin{cases} \frac{d\psi_0}{dz}(z_{n+1} - z_n) = iq_0\psi_0(p, n) + iq\psi_{\overrightarrow{g}}(p+2, n) \\ \frac{d\psi_{\overrightarrow{g}}}{dz}(z_{n+1} - z_n) = i(q_0 + \phi)\psi_{\overrightarrow{g}}(p+2, n) + iq\psi_0(p, n) \end{cases}$$

nembering:
$$z_{n+1} - z_n = a$$
 $\frac{q_0}{a} = \frac{\pi}{\xi_0}$ $\frac{q}{a} = \frac{\pi}{\xi_{\overrightarrow{g}}}$



 $\begin{cases} \frac{d\psi_0}{dz} = i\frac{\pi}{\xi_0}\psi_0 + i\frac{\pi}{\xi_{\overrightarrow{g}}}\psi_{\overrightarrow{g}} \\ \frac{d\psi_{\overrightarrow{g}}}{dz} = i\left(\frac{\pi}{\xi_0} + 2\pi s\right)\psi_{\overrightarrow{g}} + i\frac{\pi}{\xi_{\overrightarrow{g}}}\psi_0 \end{cases} \quad \sigma = \frac{\sqrt{2\pi}}{\sigma}$

 $1 + (s\xi_{\overrightarrow{g}})^2$





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Diffracted intensities in 2-beams dynamical theory : the dynamical rocking curve

$$I_{\overline{g}} = \frac{\cos^{2}(\pi\sigma t) + \left(\frac{s}{\sigma}\right)^{2} \sin^{2}(\pi\sigma t)}{I_{\overline{g}}}$$

$$I_{\overline{g}} = \frac{\sin^{2}(\pi\sigma t)}{(\sigma\xi_{\overline{g}})^{2}}$$

$$I_{\overline{g}}(t, s)$$





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Comparison (again) between kinematical and dynamical rocking curves INSA cris















2 Diffraction contrast imaging in perfect crystal

DF-DF imaging Bend contours Thickness fringes











Bright field vs dark field imaging : diffraction contrast

B. With contrast aperture (bright field)











C. *With* contrast aperture (bright field)



Bright field vs dark field imaging : diffraction contrast



D. *With* contrast aperture (Dark field)

By selecting the diffracted beam we can observed A dark field contrast reversed from the BF.

$$C = \frac{|I_d - I_m|}{I_m}$$

Contrast C is optimum in dark field

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Bright field vs dark field imaging : diffraction contrast



Bright Field (BF)





Dark Field (DF)

Dark field imaging : important practical consideration

DF with aperture shift (not good)



DF with tilted illumination (good)

Thickness fringes : kinematical approach

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Thickness fringes : kinematical approach including absorption

3 Diffraction theory of faulted crystal

- Let's consider an incoming plane wave $|\psi_0| = 1$ on a crystal define by a thickness t

Kinematical simulation of faulted crystal

• In the kinematical approximation, after Huygens-Fresnel, the diffracted wave will be given by :

$$\frac{i\pi}{z}\int_{0}^{t}e^{-2\pi i(\vec{g}+\vec{s})\cdot\vec{r}'}dz$$

• Consider now any crystal defect which shift the atomic sites by a fault vector

$$\vec{r}' \to \vec{r} + \overrightarrow{R}(z)$$

Because of column approximation : $\vec{s} \cdot \vec{r} = sz$ and $\vec{s} \cdot \vec{R} \approx 0$

$$\psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_0^t e^{-2\pi i(sz+\overrightarrow{g},\overrightarrow{R(z)})} dz$$

• Usually we define the phase term : $\alpha(z) = 2\pi \overrightarrow{g} \cdot \overrightarrow{R}(z)$ = $\frac{i\pi}{\xi_{\overrightarrow{g}}} \int_{0}^{t} e^{-2\pi i s z} e^{-2\pi i \overrightarrow{g} \cdot \overrightarrow{R}(z)} dz$

$$\Psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_0^t e^{-2\pi i s z} e^{-i\alpha(z)} dz$$

Application to stacking fault

In FCC for instance a stacking fault moves :

- *B* layer in the *C* position by applying the displacement vector : $\overrightarrow{R}(z) = \frac{a\{112\}}{6}$
- The stacking becomes : *ABCA* | *CABC*

 $2\pi \overrightarrow{g} \cdot \overrightarrow{R}(z) = 0 \Leftrightarrow -\frac{t}{2} \leq z \leq z_1$ $= \alpha \Leftrightarrow z_1 \leq z \leq \frac{l}{2}$

The stacking fault is horizontal and located at $t = t_1$ The phase shift is $\alpha = -\frac{2\pi}{3}$

• Let's go back to the kinematical expression of the diffracted wave :

Estimation of stacking fault diffraction contrast using APD : exercice

Consider sample thickness t = 30nm, with inclined stacking fault with SF vector $\vec{R} = \frac{1}{4}$ [110]

DF image with $\overrightarrow{g} = 200$ and s = 0.05 nm⁻¹

Use amplitude phase diagram (APD) to determine ratio of DF image intensities for the columns. Assume kinematical approximation valid.

Possible answers:

 $1 \to I(A) > I(B) > I(C)$ $2 \to I(A) = I(C) > I(B)$ $3 \rightarrow I(A) = I(C) = I(B)$

Hint: convert thickness change to fraction of circumference = -S

Estimation of stacking fault diffraction contrast using APD : exercice

Consider sample thickness t = 30nm, with inclined stacking fault with SF vector $\vec{R} = \frac{1}{4}$ [110]

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DF image with $\overrightarrow{g} = -100$ and s = 0.05 nm⁻¹

 $1 \to I(C) > I(A); I(B) = 0$ $2 \to I(A) = I(C); I(B) = 0$ Possible answers: $3 \rightarrow I(C) > I(B); I(A) = 0$

Estimation of stacking fault diffraction contrast using APD : real cases

Various configuration :

Constant contrast

Invisible

Kinematical simulation of an inclined stacking fault

Kinematical vs dynamical theory in diffraction contrast

Interpreted as anomalous absorption of Bloch waves in dynamical 2 beams theory

Diffraction contrast Imaging in faulted crystal

BF-DF imaging vs weak beam Dislocations Stacking fault Antiphrase boundaries Grain boundaries etc.

Conventional observation of stacking fault

Same area of a Si sample imaged with two different diffraction vectors of the $\{220\}$ type

Phase shift $\alpha = 2\pi \cdot \overrightarrow{g} \cdot \overrightarrow{R} \neq 0$

Phase shift $\alpha = 2\pi . \overrightarrow{g} . \overrightarrow{R} = 0$

Conventional observation of Moiré fringes

$$\Psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_0^{t_1} e^{-2\pi i s z} dz + \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_{t_1}^{t_2} e^{-2\pi i s z} e^{-i\alpha(z)} dz$$

Conventional observation of Moiré fringes

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Conventional observation of grain boundaries

Conventional observation of antiphase boundaries

Fringes contrast : same interpretation as for stacking fault

Extracted from : P. Zhao, L. Feng, K. Nielsch, T.G. Woodcock, Microstructural defects in hot deformed and as-transformed τ-MnAl-C, Journal of Alloys and Compounds, Volume 852, 2021, 156998, https://doi.org/10.1016/j.jallcom.2020.156998.

$$\frac{1-2\nu}{2(1-\nu)}\ln(r) + \frac{\cos(2(\Phi-\gamma))}{4(1-\nu)} \bigg] \bigg) \quad \clubsuit$$

 b_e is the edge component of dislocation

$$\pi \overrightarrow{g}$$
. $R(z) \rightarrow \text{If } \overrightarrow{g}$. $\overrightarrow{b} = 0 \implies \alpha = 0$ and the dislocation is invisible

- The planes are bent around the core of the dislocation •
- On one side of the dislocation, the planes might be bent closer to the Bragg condition • \implies s is smaller) such that the intensity, $I_{\overrightarrow{g}}$ is higher than the background
- On the other side of the dislocation, the planes would be bent away from the • Bragg condition, therefore $I_{\overrightarrow{g}} \approx I_{background}$
- Dislocations parallel to the surface show uniform contrast, inclined dislocations • alternating contrast
- Reversing either \overrightarrow{g} or \overrightarrow{s} will reverse the position of the image of the dislocation relative to the dislocation core

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Conventional observation of dislocations

$$\psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_{0}^{t} e^{-2\pi i s z} e^{-2\pi i \overrightarrow{g} \cdot \overrightarrow{R(z)}} dz$$

$$\psi_{\overrightarrow{g}} = \frac{i\pi}{\xi_{\overrightarrow{g}}} \int_{-z_1}^{z_2} \exp\left(-i\left(2\pi sz + n\arctan\left(\frac{z}{x}\right)\right)\right) dz$$

Typical values for metals (fcc) with
$$\vec{b} = \frac{1}{2}[110]$$

• If $\overrightarrow{g} = (1\overline{1}1) \implies \overrightarrow{g} \cdot \overrightarrow{b} = 0$ the dislocation is invisible

• If
$$\overrightarrow{g} = (111) \implies \overrightarrow{g} \cdot \overrightarrow{b} = 1$$

For
$$\overrightarrow{g} \cdot \overrightarrow{b} = 1$$
 the image width is $\Delta x_p \approx \frac{1}{2\pi s}$ and the image po
For example
• If $\overrightarrow{g} \cdot \overrightarrow{b} = 2 \implies \Delta x_p \approx \frac{1}{\pi s}, x_p = -\frac{1}{2\pi s}$ For $\overrightarrow{g} = 0$

Thus the pick width is such smaller and the peak much closer to the core for large values of s. This is the principe of weak beam imaging.

Caution : choose s carefully as $I_{\overrightarrow{g}} \propto \frac{1}{s^2}$. Furthermore kinematic approximation holds well for large s. When $s \to 0$ dynamical theory must be use

Diffraction contrast of dislocation : some order of magnitude

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Weak beam imaging : $\overrightarrow{g} - n \overrightarrow{g}$ conditions

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Weak beam imaging :some examples

Characterization of dislocation using CTEM

Screw Dislocations in Si

Two BF images taken with different diffraction conditions

$$\cdot \overrightarrow{g} = 022$$

 $\cdot \overline{g} = 311$

→The dislocation marked A is invisible in (b)

Edge dislocations

Edge dislocations are not as straightforward Even if \overrightarrow{g} . $\overrightarrow{b} = 0$, then there might still be some component of displacement causing diffraction from the \overrightarrow{g} . $(\overrightarrow{b} \wedge \overrightarrow{L}) = 0$ term

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Characterization of dislocation using CTEM : exercice

			Taken from A. Put to Mineral Science	nis Introduction s, 1992, CUP g=044		g=113		g=131		
			g=004		2 3 2		g=040			
\overrightarrow{g}	\overrightarrow{b}	$\frac{1}{2}$ [110]	$\frac{1}{2}$ [101]	$\frac{1}{2}[011]$	$\frac{1}{2}$ [1 $\bar{1}0$]	$\frac{1}{2}[10\overline{1}]$	$\frac{1}{2}[01\overline{1}]$	1	2	3
131		2	0	1	-1	1	2	INVIS	VIS.	VIS
040		2	0	2	-2	0	2	INVIS	VIS.	VIS
113		0	2	1	1	-1	-2	VIS.	INVIS	VIS
004		0	-2	-2	0	2	2	VIS.	INVIS	VIS
044		2	2	4	-2	-2	0	VIS.	VIS	INVIS

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Characterization of dislocation using CTEM : solution

 $\overrightarrow{b}_1 = \frac{a}{2}[101]$ $\overrightarrow{b}_2 = \frac{a}{2}[110]$ $\overrightarrow{b}_3 = \frac{a}{2}[01\overline{1}]$

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Conventional observation of precipitates

Bright field

Dark Field

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Understanding diffraction contrast in CTEM requires an understanding of how diffraction intensities are generated Diffraction Bright field

Conclusion

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Thank you

Le calcul de l'intégrale double se découple en un produit de deux intégrales simples (théorème de Fubini)

 $\psi(M) = K(\theta)\psi_0 2\pi \int_{\rho=0}^{a} \frac{e^{-ik\sqrt{\rho^2 + z^2}}}{\sqrt{\rho^2 + z^2}} \rho d\rho d\theta = K(\theta)\psi_0 2z$

$$\int_{\theta=0}^{2\pi} \int_{\rho=0}^{a} \frac{e^{-ik\sqrt{\rho^2 + z^2}}}{\sqrt{\rho^2 + z^2}} \rho d\rho d\theta$$

$$2\pi \left[\frac{i}{k}e^{-ik\sqrt{\rho^2+z^2}}\right]_0^a$$